Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	(("5188973") or ("5773331")).PN.	USPAT	OR	OFF	2005/10/30 19:41
L2	16573	((438/149) or (438/174) or (438/176) or (438/180) or (438/181) or (438/184) or (438/185) or (438/197) or (438/199) or (438/201) or (438/207) or (438/211) or (438/213) or (438/217) or (438/218) or (438/221) or (438/222) or (438/229) or (438/230) or (438/231) or (438/233) or (438/260) or (438/265) or (438/276) or (438/289) or (438/294) or (438/296) or (438/299) or (438/300) or (438/301) or (438/303) or (438/311) or (438/318) or (438/320) or (438/364) or (438/406) or (438/413) or (438/416) or (438/429) or (438/430) or (438/459) or (438/488) or (438/491) or (438/532) or (438/597) or (438/607) or (438/704)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/30 20:55
L3	749	2 and (((front and back) or (bottom and top)) near5 (gate$1 or (gate adj electrode$1)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:39
L4	749	2 and (((front and back) or (bottom and top)) near5 (gate$1 or (gate adj electrode$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:34
L5	497	4 and (align$4 or (self adj align$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:40
L6	45	5 and (chemical and isotropic and ("RIE" or (reactive adj ion)) near5 etch$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:40

L7	1029	2 and (((front and back) or (bottom and top) or double$2) near3 (gate$1 or (gate adj electrode$1)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:45
L8	696	7 and (align$4 or (self adj align$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:59
L9	53	8 and (chemical and isotropic and ("RIE" or (reactive adj ion)) near5 etch$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:45
L10	1	("5858821").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/10/30 20:43
L11	5	("6339002").URPN.	USPAT	OR	OFF	2005/10/30 20:43
L12	14756	(((front and back) or (bottom and top) or double$2) near3 (gate$1 or (gate adj electrode$1)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:58
L13	6472	12 and (align$4 or (self adj align$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:45
L14	246	13 and (chemical and isotropic and ("RIE" or (reactive adj ion)) near5 etch$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:59
L15	193	14 not 9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 21:00

L16	17471	((438/149) or (438/174) or (438/176) or (438/180) or (438/181) or (438/184) or (438/185) or (438/197) or (438/199) or (438/201) or (438/207) or (438/211) or (438/213) or (438/217) or (438/218) or (438/221) or (438/222) or (438/229) or (438/230) or (438/231) or (438/233) or (438/259) or (438/260) or (438/262) or (438/265) or (438/276) or (438/283) or (438/289) or (438/294) or (438/296) or (438/299) or (438/300) or (438/301) or (438/303) or (438/304) or (438/311) or (438/318) or (438/320) or (438/364) or (438/406) or (438/413) or (438/416) or (438/429) or (438/430) or (438/459) or (438/488) or (438/491) or (438/532) or (438/597) or (438/607) or (438/704)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/30 21:11
L17	1188	16 and (((front and back) or (bottom and top) or double$2) near3 (gate$1 or (gate adj electrode$1)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 21:12
L18	77	17 and (chemical and isotropic and ("RIE" or (reactive adj ion)) near5 etch$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 21:12
L19	60	18 and (align$4 or (self adj align$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 21:12
L20	53	19 not 15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 21:02

L21	295	(438/283).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/30 21:09
L22	1508	(438/149).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/30 21:10
L23	538	(438/299).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/30 21:11
L24	425	(438/704).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/30 21:11
L25	18405	((438/149) or (438/174) or (438/176) or (438/180) or (438/181) or (438/184) or (438/185) or (438/197) or (438/199) or (438/201) or (438/207) or (438/211) or (438/213) or (438/217) or (438/218) or (438/221) or (438/222) or (438/229) or (438/230) or (438/231) or (438/233) or (438/259) or (438/260) or (438/262) or (438/265) or (438/276) or (438/283) or (438/289) or (438/294) or (438/296) or (438/299) or (438/300) or (438/301) or (438/303) or (438/304) or (438/311) or (438/318) or (438/320) or (438/364) or (438/406) or (438/413) or (438/416) or (438/429) or (438/430) or (438/459) or (438/488) or (438/491) or (438/532) or (438/597) or (438/607) or (438/700) or (438/704)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/30 21:11

L26	1198	25 and (((front and back) or (bottom and top) or double$2) near3 (gate$1 or (gate adj electrode$1)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 21:12
L27	78	26 and (chemical and isotropic and ("RIE" or (reactive adj ion)) near5 etch$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 21:12
L28	61	27 and (align$4 or (self adj align$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 21:13
L29	1038	(438/700).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/30 21:13
S1	13657	((438/149) or (438/174) or (438/176) or (438/180) or (438/181) or (438/184) or (438/185) or (438/197) or (438/199) or (438/201) or (438/207) or (438/211) or (438/213) or (438/217) or (438/218) or (438/221) or (438/222) or (438/229) or (438/230) or (438/231) or (438/233) or (438/260) or (438/265) or (438/276) or (438/289) or (438/294) or (438/296) or (438/299) or (438/300) or (438/301) or (438/303) or (438/311) or (438/318) or (438/320) or (438/364) or (438/406) or (438/413) or (438/416) or (438/429) or (438/430) or (438/459) or (438/488) or (438/491) or (438/532) or (438/597) or (438/607) or (438/704)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/30 20:29
S2	31127	soi or (silicon near2 insulator)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 10:48

S3	109204	cmos or (complementary near (metal near2 oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:31
S4	2814	simox or (separation adj ion adj implantation adj oxygen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:32
S5	1333	(front and back) near5 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 20:32
S6	154699	gate near5 (dielectric or insulat$3 or oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:34
S7	85681	trench$2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:34
S8	4	sacrifical near3 spacer$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 21:21
S9	10	sacrifical same spacer$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:35
S10	7641	(soi or (silicon near2 insulator)) and (cmos or (complementary near (metal near2 oxide)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:36
S11	1178	((soi or (silicon near2 insulator)) and (cmos or (complementary near (metal near2 oxide)))) and (simox or (separation adj ion adj implantation adj oxygen))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:43
S12	32	(((soi or (silicon near2 insulator)) and (cmos or (complementary near (metal near2 oxide)))) and (simox or (separation adj ion adj implantation adj oxygen))) and ((front and back) near5 gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:43

S13	32	((((soi or (silicon near2 insulator)) and (cmos or (complementary near (metal near2 oxide)))) and (simox or (separation adj ion adj implantation adj oxygen))) and ((front and back) near5 gate))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:44
S14	0	((((((soi or (silicon near2 insulator)) and (cmos or (complementary near (metal near2 oxide)))) and (simox or (separation adj ion adj implantation adj oxygen))) and ((front and back) near5 gate)) and (gate near5 (dielectric or insulat$3 or oxide))) and trench$2) and (sacrifical same spacer$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:45
S15	16	(((((soi or (silicon near2 insulator)) and (cmos or (complementary near (metal near2 oxide)))) and (simox or (separation adj ion adj implantation adj oxygen))) and ((front and back) near5 gate)) and (gate near5 (dielectric or insulat$3 or oxide))) and trench$2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:53

S16	1	((((((soi or (silicon near2 insulator)) and (cmos or (complementary near (metal near2 oxide)))) and (simox or (separation adj ion adj implantation adj oxygen))) and ((front and back) near5 gate)) and (gate near5 (dielectric or insulat$3 or oxide))) and trench$2) and (((438/149) or (438/174) or (438/176) or (438/180) or (438/181) or (438/184) or (438/185) or (438/197) or (438/199) or (438/201) or (438/207) or (438/211) or (438/213) or (438/217) or (438/218) or (438/221) or (438/222) or (438/229) or (438/230) or (438/231) or (438/233) or (438/260) or (438/265) or (438/276) or (438/289) or (438/294) or (438/296) or (438/299) or (438/300) or (438/301) or (438/303) or (438/311) or (438/318) or (438/320) or (438/364) or (438/406) or (438/413) or (438/416) or (438/429) or (438/430) or (438/459) or (438/488) or (438/491) or (438/532) or (438/597) or (438/607) or (438/704)).CCLS.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 20:47
S17	9	("6074209" | "6275094" | "6359312" | "6383904" | "6391695" | "6392277" | "6423599" | "6432754" | "6441436").PN.	USPAT	OR	OFF	2004/07/31 21:11
S18	16	("3853633" | "4222062" | "4393578" | "4839707" | "4951123" | "5166765" | "5273921" | "5285352" | "5376578" | "5482871" | "5726459" | "5780912" | "6008126" | "6057555" | "6074920" | "6166412").PN.	USPAT	OR	OFF	2004/07/31 21:14
S19	9	("6074209" | "6275094" | "6359312" | "6383904" | "6391695" | "6392277" | "6423599" | "6432754" | "6441436").PN.	USPAT	OR	OFF	2004/07/31 21:17

S20	7	("5164805" | "5885887" | "6204138" | "6284594" | "6359298" | "6365450" | "6376312").PN.	USPAT	OR	OFF	2004/07/31 21:19
S21	350479	spacer$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 21:21
S22	9	("4601779" | "5273921" | "5296727" | "5461250" | "5497019" | "5604368" | "5681775" | "5929479" | "6248637").PN.	USPAT	OR	OFF	2004/07/31 21:23
S23	32	(((((soi or (silicon near2 insulator)) and (cmos or (complementary near (metal near2 oxide)))) and (simox or (separation adj ion adj implantation adj oxygen))) and ((front and back) near5 gate)) and (gate near5 (dielectric or insulat$3 or oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/07/31 21:28
S24	4	("5291047" | "5446299" | "5488243" | "5751037").PN.	USPAT	OR	OFF	2004/07/31 21:31
S25	19	"5929479".URPN.	USPAT	OR	OFF	2004/07/31 21:32
S26	14546	((438/149) or (438/174) or (438/176) or (438/180) or (438/181) or (438/184) or (438/185) or (438/197) or (438/199) or (438/201) or (438/207) or (438/211) or (438/213) or (438/217) or (438/218) or (438/221) or (438/222) or (438/229) or (438/230) or (438/231) or (438/233) or (438/260) or (438/265) or (438/276) or (438/289) or (438/294) or (438/296) or (438/299) or (438/300) or (438/301) or (438/303) or (438/311) or (438/318) or (438/320) or (438/364) or (438/406) or (438/413) or (438/416) or (438/429) or (438/430) or (438/459) or (438/488) or (438/491) or (438/532) or (438/597) or (438/607) or (438/704)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/29 10:48

S27	69788	soi or (silicon near2 insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 10:49
S28	2565	S26 and S27	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 10:49
S29	14	S28 and (front and back) near5 gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/29 10:49
S30	5	(("6580132") or ("6528376") or ("6339002") or ("5773331") or ("5346839")).PN.	USPAT	OR	OFF	2005/10/28 20:51